# Noise in Microwove Systems

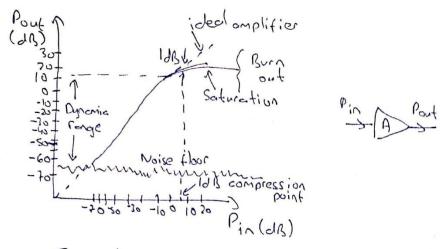
Noise can be passed into a microwove system from external sources or generated within the system itself. The noise level of a system sets the lower limit on the strength of a signal that can be detected. It is generally desired to minimize the noise level of a receiver to achieve the best performance.

## Dynamic range and sources of noise

For a component, there is a range of signal levels over which deterministic and linear assurptions are valid; this range is called the dynamic range of the component.

(Linear: the output is directly proportional to the input )

(Deterministic: the output is predictable from the input)



Consider a microwave transistor amplifier having a gain of KdB, as shown in Figure. At very low input power levels, the output will be dominated by the noise of the amplifier. This level is often called the noise floor of the component or system. Above the noise floor, the amplifier has a range of input powers for which Pout = KPin is closely approximated. This is the usabe dynamic range of the component.

At the upper end of the dynamic range, the output begins to saturate, meaning that the output power no longer increases linearly as the input power increases. I dB compression point is defined as the input power level for which the output is I dB below that of the ideal omplifier. If the input power is excessive, the amplifier can be destroyed.

Here, the dynamic range is defined as the difference of the output powers which are the output power corresponding to the L dB compression point and the output power corresponding to the noise floor.

Noise is usually generated by the random motions of carries in devices and materials. charges or charge There are several sources of noise:

· Thermal noise: ( Johnson or Nyquist noise) caused by thermal vibration of bound changes.

caused by the random fluctuations of charge corriers in an electron tube a solid-state device. . Shot noise:

· Flicker noise: ( "If noise) Occurs in solid-state components and varies and varies with frequency.

. Plasma noise: Caused by random motion of charges in an ionized gas.

· Quantum noise: Results from the quantized nature of charge carriers and photons.

### Noise power and equivalent noise temperature

Consider a resistor at a temperature of T (%) as depicted in the figure. The electrons in this resistor are in random

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radiation law,

motions that produce small, random voltage fluctuations that is proportional to the temperature at the resistor terminals. This voltage has a value given by Planck's black body

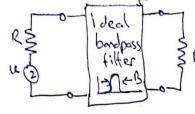
> h=6,566.10-34 J-sec : Planck's constant k=1,380.10-23 J/OK : Boltzmann's " Tis the temperature (41) B is the bondwidth of the system (Hz) f is the center frequency of the bandwidth (H) R is the resistance (S.)

At microwave frequencies this result can be simplified by making use of the fact that hf ZZLT. Using the first two terms of a Toylor series for the exponential gives,

ehf/lit-1 = hf and the above result reduces to Un = VALTBR

This is the Rayleigh-Jeans approximation and valid in microwave region. Such a noise has a power spectral density which is independent of frequency is referred to as a white roise.

The noisy resistor can be replaced with a Thevenin equivalent circuit consisting of a noiseless resistor and a generator with a voltage u. Connecting a load resistor R results in



Ideal maximum power transfer from the bodiess of noisy resistor. The power delivered to the load is then. the load is then,

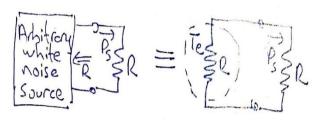
$$P_{n} = \left(\frac{u_{n}}{2R}\right)^{2} R = \frac{u_{n}^{2}}{4R} = LTB$$

- · As B -> 0, Pn->0
- · As T-0, Pn-0
- · As B -> 00, Pn -> 00

(systems with smaller B collect less noise pour) (cooler devices generate less noise power) does not occur in reality because the obove app. is not valid as f-200. The first form for un must be used in this case.

If an arbitrary source of noise is "white", it can be modeled as an equivalent thermal noise source, such as a noisy resistor R, and characterized with temperature Te where Te is an equivalent noise temperature.

Te is selected so that the some noise power is delivered to the local, that is,



Consider a noisy amplifier with a bandwidth B and gain G. Let the amplifier be matched to noiseless source with temperature of Ts = 0°K, then the Pi to the amplifier will be zero and the Po will be due only to the noise generated by the amplifier itself.

We can obtain the same Po by driving an ideal noiseless amplifier with a resistor at temperature Te,

so that the Po in both cases is GILTEB. Here, To is the equivalent noise temperature of the amplifier.

In practice, the 09k source temperature cannot be achieved then the Y-factor method can be applied to determine the Te of a component. Let the amplifier be matched to two loads of temperatures  $T_1$  and  $T_2$   $(T_1 > T_2)$ . Output powers will be,

Define the Y-factor as

$$Y = \frac{\rho_1}{\rho_2} = \frac{T_1 + Te}{T_2 + Te} > 1$$

which is determined via the power measurements. Then

Te will be,
$$T_e = \frac{T_1 - YT_2}{Y - 1}$$

Example:

For an X-band amplifier, G=20 dB and B=1 GHz. The following data is obtained:  $T_1=290$  9L  $\rightarrow$   $P_1=-62.0$  dBm  $T_2=77$  K  $\rightarrow$   $P_2=-64.7$  dBm

Determine the Te of the emplifier. It the source has Ts=450°k,

$$Y = (P, -P_2) dB = (-62) - (-64.7) = 2,7 dB = 1,86$$
 (numeric volue)  
 $Te = T_1 - YT_2 = \frac{290 - (1,86)(77)}{1,86 - 1} = 170 \text{ °K}$   
 $P_0 = GLT_5B + GLT_6B = 100 (1,38.10^{-23})(10^9)(450 + 170)$   
 $= 8.56.10^{-10} \text{ W} = -60.7 dBm$ 

#### Noise figure

When noise and a desired signal are applied to the input of a noisy network, the output noise power will be increased more than the output signal power, so that the output signal-to-noise ratio will be reduced. The noise figure, F, is a measure of this reduction in SIN and is defined as

$$F = \frac{S_i/N_i}{S_0/N_0} > 1$$

By definition, N; is assumed to be the noise power resulting from a motched resistor at To=290 °K; that is, N;=1cToB.

Consider the figure below. The input noise power is NizkToB and the output noise power is a sum of the amplified input noise with the gain G and the noise generated by the noisy network: No = IcGB(To+Te). The output signal power is So=GSi. The noise figure F will be,

$$F = \frac{S_i / kT_0B}{GS_i / kGS(T_0 + T_e)} = 1 + \frac{T_e}{T_0} \ge 1$$

$$In JB, F = 10 \log (1 + T_e/T_0) JB \ge 0$$

If the network were noiseless, Te would be zero, giving F=1 (0 dB). Using above equation, Te will be,

An important special case occurs in practice when the two-port network is a passive, lossy component held at a temperature T. The loss factor, L, can be defined as L=1/6>1.

Because the entire system is in thermal equilibrium of T and has driving point impedenced , the output noise power must be Po=lits. This power comes from the source resistor and from the noise generated by the line itself. Thus,

Po = KTB = GKTB + GNadded

Solving this equation for Moddad,

$$N_{\text{odded}} = \frac{1-G}{G} LTB = (L-1) LTB.$$

This result shows that the lossy line has on Te given by

and using F = 1 + Te/To, the noise figure F is,  $F = 1 + (L-1) \frac{T}{To}$ 

- If the line is at temperature To, then F=L

#### Exomple

A 10-12 GHz emplifier has a gain of 20 dB, a noise figure of 3.5 dB and an output power of 10 dBm of its 1 dB compression point. What is the dynamic range of this emplifier?

The upper end of the dynamic range is 10 dBm corresponding to 1 dB comp. point. The lower end is set by the output noise power No, due to the amplifier itself.

The equivalent noise temperature of the amplifier is  $Te = (F-1)T_0 = (10^{3.5/10}-1)290 = 359 \text{ °K}$ 

The output noise power is 1

No = GlcTeB = 20 + 10 log  $\frac{(1.38.10^{-23})(359)(2.10^9)}{10^{-3}W}$ = -60.0 dBm

So the dynamic rang is

10 dBm - (-60.0dBm)

= 70.0 dB

#### Noise figure of a cascaded system

If we know the F (or Te) of the individual stages, we can determine the F (or Te) of the coscade connection of stages.

Consider the two coscoded networks as shown the figure below, we wish to find the overall Foos and Tecos as if it were a single component.

$$\frac{N_1}{T_0} = \frac{N_1}{F_1, T_{e_1}} = \frac{N_1}{T_0} = \frac{N_1$$

The noise power at the output of the first stage is

and the second stage is

$$N_0 = G_2 N_1 + G_2 |_{Ce_2 B} = G_1 G_2 |_{CB} (T_0 + T_{e_1} + \frac{1}{G_1} T_{e_2})$$
  
=  $G_1 G_2 |_{CB} (T_{cos} + T_0)$ 

where the noise temperature of the cascade system is,  $T_{CGS} = T_{E_1} + \frac{1}{G_1} T_{E_2}$ 

is, and using F = 1 + Te/To, the noise figure of the coscool system  $F_{cos} = F_1 + \frac{1}{G_1} (F_2 - 1)$ 

These equotions show that the noise characteristics of a cascaded system are dominated by the characteristics of the first stage. For the best system noise performance, the first stage should have a low noise figure and of least moderate gain.

These equations can be generalized to an orbitrary number of stages, as follows:

$$T_{cos} = T_{e_1} + \frac{T_{e_2}}{G_1} + \frac{T_{e_3}}{G_1G_2} + \cdots$$

$$F_{cos} = F_1 + \frac{F_2 - I}{G_1} + \frac{F_3 - I}{G_1G_2} + \cdots$$

Example:

An antenna is connected to a low-noise amplifier with a piece of cooxial transmission line. The amplifier parameters are; G=15 dB, B=100 MHz, Te=150 9K. The cooxial line has on attenuation of 2 dB. Find the F of the coscaded network. What would be the F if the amplifier were placed of the antenna, eliminating the transmission line? Assume all components are at an ambient temperature of T=300°K

The loss factor of the line is  $L=10^{2/10}=1.58$ , and the F of the line is

 $F_p = 1 + (L-1) \frac{T}{10} = 1 + (1.58 - 1) \frac{300}{290} = 1.60 = 2.04 dB$ The F of the omplifier is:

$$F_a = 1 + \frac{Te}{To} = 1 + \frac{150}{290} = 1.52 = 1.81 \text{ JB}$$

The Fof the coscode is,

$$F_{cas} = F_{p} + \frac{1}{G_{p}} (F_{q-1}) = 1,60 + 1,58 (1,52 - 1) = 2,42$$

$$= 3.84 dR$$

Without the transmission line, F would be that of the amplifier itself, or 1.81 dB. We see that the effect of the lossy line reduces the F of the system by about 2 dB.